

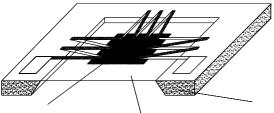
sensor-ic.com/ TEL:0755-83376549 FAX:0755-8 <u>HLPLANAR</u> Thermosensors TS 118-3/TS 118-4

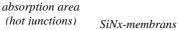
THERMOPILES are used for non-contact surface temperature measuring.

Any object emits infrared radiation. The radiation power is increasing with growing surface temperatures. Based on this relation, THERMOPILES measure the emitted power and determine the object's temperature precisely.

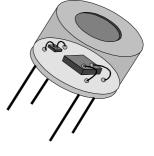
Function Principle

THERMOPILES are based on the Seebeck effect, which is used since a long time for conventional thermocouples. The application of micromechanics and thin film technology allows the production of miniaturized and cost effective sensor elements.





silizium-substraet (cold junctions)



Filter

A multitude of thermojunctions deposited on a silicon substrate is connected in series to form a THERMOPILE. The hot junctions are thermally insulated from the cold junctions on the substrate by etching a self-supporting extremely thin membrane. An absorbing layer on the hot junctions transforms the incoming radiation into heat. A voltage proportional to the radiation is generated by the thermoelectric effect. The sensors are delivered in TO05 packages. Different housings and filter types can be selected to find an optimal solution for each application. Chips without housing are available as well.

Specifications

Value Parameter Symbol Unit Condition Number of thermojunctions 100 100 п BiSb, NiCr Material 90 Active Area mm² 0.7 * 0.7 A_A 80 Chip Size mm^2 2.0 * 2.0 A_C 25 °C 70 Resistance of Thermopile $k\Omega$ 50 ±15 R (%) TCR%/K -0.03 ±0.02 +25...+75 °C TC of resistance 60 Transmission 25°C, 500 K, DC Sensitivity of sensor V/WS typical 80 50 TCS %/K -0.52 ±0.08 +25...+75 °C TC of sensitivity 40 $cm^{*}Hz^{1/2}/W$ $1.5 * 10^8$ D^* 500 K DC Specific detectivity Noise equivalent power NEP nW0.46 500 K, 1 Hz 30 500 K, 1 Hz Time constant t63 ms 40 ±10 20 Operation temperature Т $^{\circ}C$ -20 ... +100 10 Storage temperature $^{\circ}C$ -40 ... +100 T ſ **Reference** Resistor Resistance R_{Ni} Ω 1000 ±0.4% $0^{\circ}C$ 56 7 8 9 10 11 12 13 14 15 TCR_{Ni} 6178 ±1% 0 °C...100 °C TC of resistance ppm / K Wavelength (um) Function: $R(T) = 1000\Omega + 6,17*T*\Omega$, for detailled information see data sheet of reference resistor

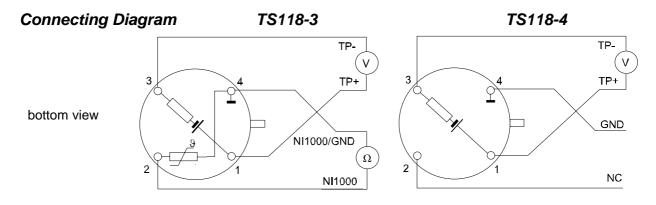
> HL-Planartechnik GmbH Hauert 13, 44 227 Dortmund, Tel.: +49 (0) 231/97400, Fax.: +49 (0) 231/974020 Internet: http://www.hlplanar.com E-Mail: service@hlplanar.de

0755-83376489 FAX:0755-833 sor-ic.com/ TEL:

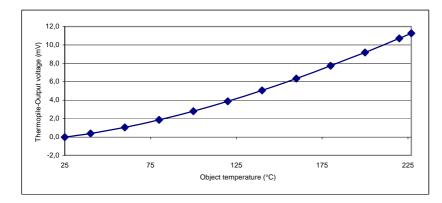


sensor-ic.com/ TEL:0755-83376549 FAX:0755-8 <u>HLPLANAR</u> Thermosensors

TS 118-3/TS 118-4



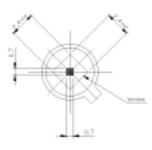
Output Voltage versus Object Temperature

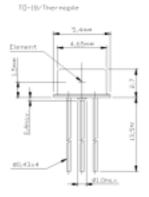


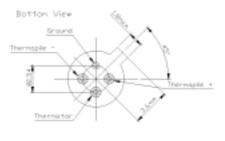
Conditions: Distance from Thermopile to Black Body is 5 cm, emissivity equals 1, surrounding temperature is 25°C

Tables with emissitvity of different materials and surface are available.

Housing TO 18







Applications

- contactless measurement of surface temperatures or IR-Radiation
- temperature measurement of moving objects
- manufacturing temperature control systems
- thermal alarm systems •
- consumer, safety- and environmental systems
- absorption measurement for gas analysis (see special data sheet)
- industrial and automotive climate control systems
- medical instruments

Additional products with different filters and packages are also available. Tables with emissivity of different materials and surfaces are available.

Specifications are subject to change without notice !

HL-Planartechnik GmbH Hauert 13, 44 227 Dortmund, Tel.: +49 (0) 231/97400, Fax.: +49 (0) 231/974020 Internet: http://www.hlplanar.com E-Mail: service@hlplanar.de

Stand: 08.04.02 Desian: Zn

0755-83376489 FAX:0755-833 sor-ic.com/ TEL: